

# isc N-Channel MOSFET Transistor

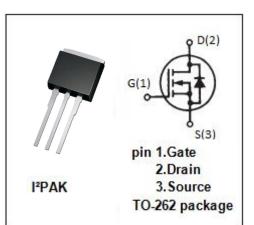
## AOW12N50

### FEATURES

- Drain Current –I\_D=12A@ T\_C=25 $^\circ\!\mathrm{C}$
- Drain Source Voltage-: V<sub>DSS</sub>=500V(Min)
- Static Drain-Source On-Resistance
- : R<sub>DS(on)</sub> = 0.52 Ω (Max)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

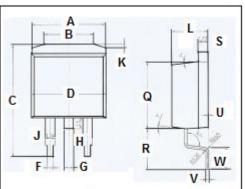
### DESCRIPTION

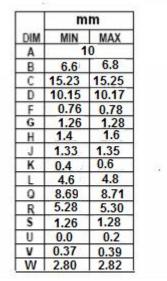
• Designed for use in switch mode power supplies and general purpose applications.



### ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

PARAMETER	VALUE	UNIT
Drain-Source Voltage	500	V
Gate-Source Voltage-Continuous	±30	V
Drain Current-Continuous	12	A
Drain Current-Single Pluse	48	A
Total Dissipation @Tc=25℃	250	W
Max. Operating Junction Temperature -55~150		°C
Storage Temperature -55~150		°C
	Drain-Source VoltageGate-Source Voltage-ContinuousDrain Current-ContinuousDrain Current-Single PluseTotal Dissipation @Tc=25°CMax. Operating Junction Temperature	Drain-Source Voltage500Gate-Source Voltage-Continuous±30Drain Current-Continuous12Drain Current-Single Pluse48Total Dissipation @Tc=25°C250Max. Operating Junction Temperature-55~150





#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case	0.5	°C/W

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### **ELECTRICAL CHARACTERISTICS**

#### $T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> = 0.25mA	500		V
V <sub>GS</sub> (th)	Gate Threshold Voltage	V <sub>DS</sub> = 5V; I <sub>D</sub> = 0.25mA	3.3	4.5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> = 6A		0.52	Ω
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> = ±30V;V <sub>DS</sub> = 0		±100	nA
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 650V; V <sub>GS</sub> = 0		1	μA
V <sub>SD</sub>	Forward On-Voltage	I <sub>S</sub> = 5.5A; V <sub>GS</sub> = 0		1	V

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